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**General Description:**

Gallium aluminum arsenide infrared emitting diode optically coupled to an electrically isolated silicon photo-darlington transistor; forward voltage 1.45 maximum volts; forward current 10.0 ma dc; 0.330 in. Lg;

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

A23900